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VS-3EYH01-M3, VS-3EYH02-M3

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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
3 A					
100 V, 200 V					
0.71 V					
70 A					
16 ns					
175 °C					
SlimSMAW (DO-221AD)					
Single					

FEATURES

Hyperfast Rectifier, 3 A FRED Pt[®]

- Low profile package
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Class 2 whisker test
- Compatible to SOD-128 package case outline
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial, and automotive applications.

MECHANICAL DATA

Case: SlimSMAW Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Dock repetitive reverse voltage	VS-3EYH01-M3	V		100	V		
Peak repetitive reverse voltage	VS-3EYH02-M3	V _{RRM}		200	v		
Average rectified forward current		I _{F(AV)} ⁽¹⁾	T _C = 137 °C	3	А		
Non-repetitive peak surge current		I _{FSM}	$T_J = 25 \ ^{\circ}C$, 10 ms sine pulse wave	70			
Operating junction and storage temperatures		T _J , T _{Stg}		-55 to +175	°C		

Note

⁽¹⁾ Mounted on infinite heatsink

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	PARAMETER		TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking VS-3EYH01-M3		V_{BR}, V_{R}	l _B = 100 μA	100	-	-		
voltage	VS-3EYH02-M3		$R = 100 \mu A$	200	-	-	v	
Forward voltage, per diode		V _F	I _F = 3 A	-	0.86	0.95	v	
			I _F = 3 A, T _J = 150 °C	-	0.71	0.79		
Reverse leakage current, per diode		1	$V_{R} = V_{R}$ rated	-	-	2	μA	
		IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	20	μA	
Junction capacitance		CT	V _R = 200 V	-	16	-	pF	

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		I _F = 1.0 A, dI _F /dt =	= 50 A/μs, V _R = 30 V	-	22	-		
		I _F = 1.0 A, dI _F /dt =	100 A/ μ s, V _R = 30 V	-	16	-		
Reverse recovery time	t _{rr}	I _F = 0.5 A, I _R = 1A,	I _{rr} = 0.25 A	-	-	30	ns	
		T _J = 25 °C		-	18	-		
		T _J = 125 °C		-	30	-		
Beek receivery ourrent		T _J = 25 °C	$ I_F = 3 \text{ A}, \\ dI_F/dt = 200 \text{ A}/\mu\text{s}, \\ V_R = 100 \text{ V} $	-	2.5	-		
Peak recovery current	I _{RRM}	T _J = 125 °C		-	4	-	A	
D	0	T _J = 25 °C		-	23	-		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	60	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to mount		R _{thJM} ⁽¹⁾	Infinite heatsink	-	12	15		
Thermal resistance, junction to ambient		R _{thJA}	Device mounted on FR4 PCB, 2 oz. standard footprint	-	120	150	°C/W	
Marking device VS-3EYH01-M3		(H01-M3		3H1				
	VS-3EYH02-M3		Case style SlimSMAW (DO-221AD)		3H2			

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC[®] 51-14 transient dual interface test method (TDIM)

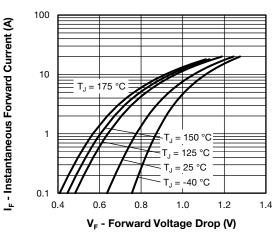


Fig. 1 - Typical Forward Voltage Drop Characteristics

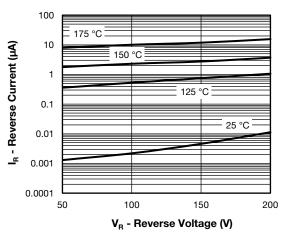
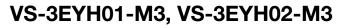


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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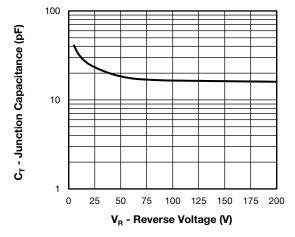


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

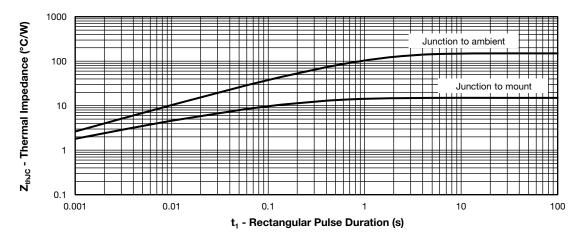
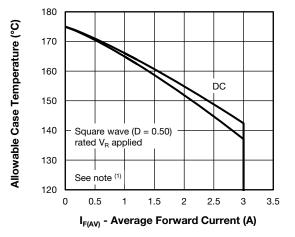
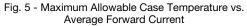


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

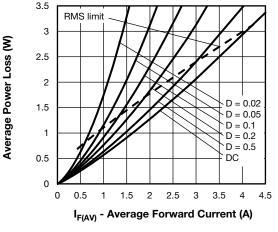


Fig. 6 - Forward Power Loss Characteristics

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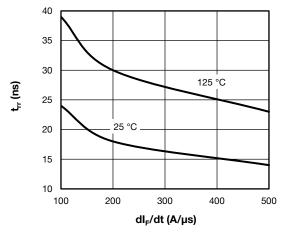
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Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

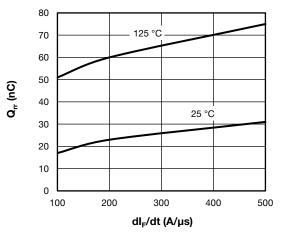


Fig. 8 - Typical Stored Charge vs. dl_F/dt

ORDERING INFORMATION TABLE

Device code	VS-	3	Е	Y	н	02	-	М3	
		2	3	4	5	6		7	-
	2	- Cur - Circ	rent rati cuit conf	niconduc ng (3 = 3 ïguratior	3 A)	oduct			
	4 · 5 ·	- Y = - Pro	E = single diode Y = SlimSMAW (DO-221AD) Process type, H = hyperfast recovery						
	6 · 7 ·		•	de (02 = en-free,		complia	nt, and	termina	tions lead (Pb

ORDERING INFORMATION (Example)										
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-3EYH01-M3/H	0.033	Н	3500	7"diameter plastic tape and reel						
VS-3EYH01-M3/I	0.033	I	14 000	13"diameter plastic tape and reel						
VS-3EYH02-M3/H	0.033	н	3500	7"diameter plastic tape and reel						
VS-3EYH02-M3/I	0.033	I	14 000	13"diameter plastic tape and reel						

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?96582						
Part marking information	www.vishay.com/doc?95562					
Packaging information	www.vishay.com/doc?88869					
SPICE model	www.vishay.com/doc?96586					

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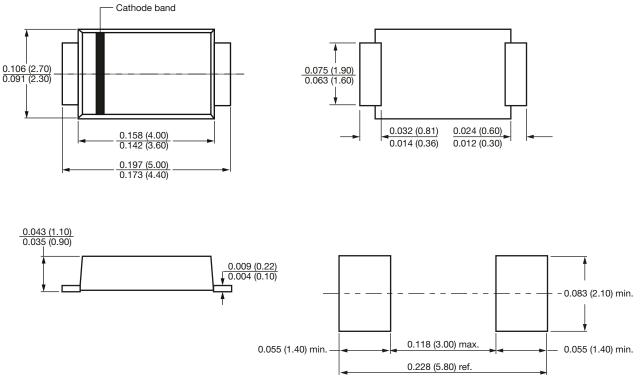
Outline Dimensions

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SlimSMAW (DO-221AD)

DIMENSIONS in inches (millimeters)

SlimSMAW (DO-221AD)



Mounting pad layout





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